



**TECH PUBLIC**

台舟电子

**ZXMN6A08E6TA**

60V N-CHANNEL ENHANCEMENT MODE MOSFET

[www.sot23.com.tw](http://www.sot23.com.tw)

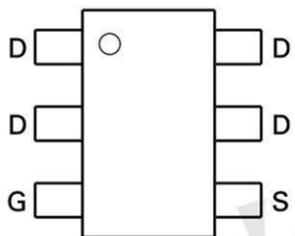
### Product Summary

- 60V/ 5A
- $R_{DS(ON)} = 25m\Omega$  ( Typ ) @  $V_{GS} = -10V$
- $R_{DS(ON)} = 30m\Omega$  (Typ ) @  $V_{GS} = -4.5V$
- Reliable and Rugged
- Lead Free and Green Devices Available  
(RoHS Compliant)

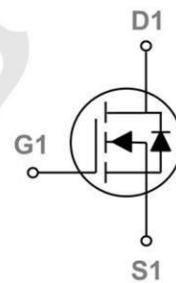
### Application

- DC-DC Converters.
- Load Switch.
- Power Management.

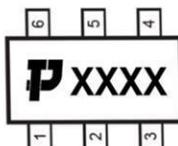
### Package and Pin Configuration



Circuit diagram



### Marking:



“P” is TECHPUBLIC LOGO

“XXXX” Marking ID (Please see the last page for details )

### Absolute Maximum Ratings ( $T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$I_D$	5	A
Pulsed Drain Current (note 1)	$I_{DM}$	30	A
Power Dissipation	$P_D$	1.7	A
Thermal Resistance from Junction to Ambient (note 2)	$R_{\theta JA}$	106	$^\circ C/W$
Junction Temperature	$T_J$	150	$^\circ C$
Storage Temperature	$T_{STG}$	-55~+150	$^\circ C$



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### Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{GS}=0\text{V}, I_D=250\mu\text{A}$	60			V
Gate-Threshold Voltage <sup>(Note3)</sup>	$V_{GS(\text{th})}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	1.0		3.0	V
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20\text{V}, V_{DS}=0\text{V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=60\text{V}, V_{GS}=0\text{V}$		1		$\mu\text{A}$
Drain-Source On-Resistance <sup>(Note3)</sup>	$R_{DS(\text{on})}$	$V_{GS}=10\text{V}, I_D=3\text{A}$ $V_{GS}=4.5\text{V}, I_D=3\text{A}$		25	29	$\text{m}\Omega$
Forward Transconductance <sup>(Note3)</sup>	$g_{fs}$	$V_{DS}=5\text{V}, I_D=4.5\text{A}$	11			S
<b>Dynamic Characteristics<sup>(Note4)</sup></b>						
Input Capacitance	$C_{iss}$	$V_{DS}=30\text{V}, V_{GS}=0\text{V}, f=1\text{MHz}$		500		pF
Output Capacitance	$C_{oss}$			60		
Reverse Transfer Capacitance	$C_{rss}$			25		
<b>Switching Characteristics<sup>(Note4)</sup></b>						
Total Gate Charge	$Q_g$	$V_{DS}=48\text{V}, V_{GS}=10\text{V}, I_D=15\text{A}$ $V_{DD}=30\text{V}, V_{GS}=10\text{V}, I_D=2\text{A}, R_G=3\Omega, R_L=6.7\Omega$		12		nC
Gate-Source Charge	$Q_{gs}$			4.1		
Gate-Drain Charge	$Q_{gd}$			4.5		
Turn-on Delay Time	$t_{d(on)}$			5.0		
Turn-on Rise Time	$t_r$			2.6		
Turn-off Delay Time	$t_{d(off)}$			16.1		
Turn-off Fall Time	$t_f$			2.3		
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage <sup>(Note3)</sup>	$V_{SD}$	$V_{GS}=0\text{V}, I_s=20\text{A}$			1.2	V
Diode Forward Current <sup>(Note2)</sup>	$I_s$				20	A
Reverse Recovery Time	$t_{rr}$	$I_F=20\text{A}, di/dt=100\text{A}/\mu\text{s}$ <sup>(Note4)</sup>		35		$\mu\text{C}$
Reverse Recovery Charge	$Q_{rr}$			53		
Forward Turn-On Time	$t_{on}$	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				



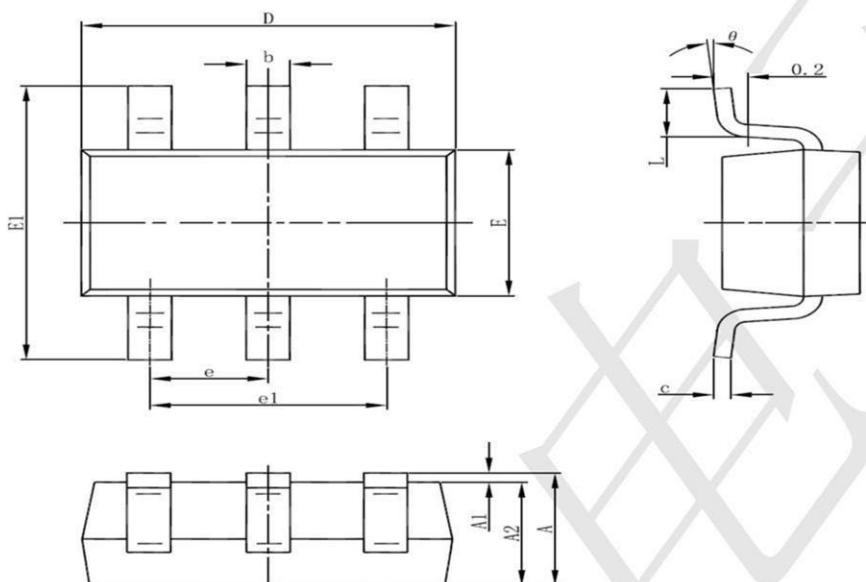
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### SOT23-6 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

### Marking:



“P” is TECHPUBLIC LOGO  
“4N” is Part number,fixed  
“xx”is internal code

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